

| 1 | INTR | NTRODUCTION | | | |
|---|------------|---|----|--|--|
| | 1.1 | CONFIDENTIALITY STATEMENT | 3 | | |
| | 1.2 | Warranty | 3 | | |
| | 1.3 | RETURNED MATERIALS | 3 | | |
| | 1.4 | Model and Revisions | 4 | | |
| | 1.5 | Environmental Considerations | 4 | | |
| | 1.6 | GENERAL SAFETY HAZARDS / PRECAUTIONS | 4 | | |
| | 1.7 | ELECTRICAL | | | |
| | 1.8 | Mechanical | | | |
| | 1.9 | THERMAL | | | |
| | 1.10 | CHEMICAL | | | |
| | 1.11 | LOCKOUT/TAGOUT PROCEDURES AND INFORMATION | | | |
| | 1.12 | Intended Use of Machine | | | |
| 2 | | IPMENT DESCRIPTION | | | |
| _ | • | | | | |
| | 2.1 | USER CONTROLS | | | |
| | 2.2 | DIMENSIONS | | | |
| | 2.3 | FEATURES & PROGRAMMABILITY | | | |
| | 2.4 | Precision | | | |
| | 2.5 | RELIABILITY | 7 | | |
| | 2.6 | UTILITIES | 7 | | |
| 3 | INST | ALLATION | 8 | | |
| | 3.1 | CLEARANCE REQUIREMENTS | 8 | | |
| | 3.2 | FACILITIES REQUIREMENTS | 9 | | |
| | 3.3 | Environment | 9 | | |
| | 3.4 | Unpackaging & Inspection | | | |
| | 3.5 | System Installation & Setup | 10 | | |
| | 3.6 | START UP | | | |
| | 3.7 | System Checks | | | |
| 4 | DAT | ASTREAM™ TECHNOLOGY | 14 | | |
| • | 4.1 | System Parameters | | | |
| | 4.1 | MANUAL CONTROLS — APOGEE™ 300 BAKE PLATE | | | |
| | | Preparation | | | |
| | 4.3 4.4 | RUNNING RECIPES | | | |
| | | EDITING RECIPES | | | |
| | 4.5 | Tool Specific Settings — Apogee™ 300 Bake Plate | | | |
| | 4.6 | | | | |
| 5 | BAKI | PLATE THEORY | 23 | | |
| | 5.1 | BAKE PLATES VS CONVENTIONAL OVENS | | | |
| | 5.2 | THE SKIN EFFECT | 23 | | |
| | 5.3 | HOTPLATE BAKE VARIABLES AND METHODS | 24 | | |
| | 5.4 | Bake Temperature | 24 | | |
| | 5.5 | Bake Methods | 24 | | |
| | 5.6 | Bake Time | 25 | | |
| | 5.7 | EXHAUST COVER | 25 | | |
| | 5.8 | OVEN VS BAKE PLATE EXAMPLES | 26 | | |
| | 5.9 | Reflow Soldering | 26 | | |
| | 5.10 | BAKE PLATE PROCESS TROUBLESHOOTING. | 26 | | |

| 6 | PREV | /ENTATIVE MAINTENANCE | . 27 |
|---|------|--------------------------------|------|
| | 6.1 | SAFETY CHECKS | . 27 |
| | 6.2 | MECHANICAL/UTILITIES CHECKLIST | . 27 |
| | 6.3 | Cleaning | . 28 |
| 7 | TABL | LE OF REVISIONS | . 29 |

1 Introduction

1.1 Confidentiality Statement

Information supplied is for the use in the operation and/or maintenance of Cee® equipment. Neither this document nor the information it contains shall be disclosed to others for manufacturing or any other purpose without written authorization from, Cost Effective Equipment, LLC.

1.2 Warranty

Cost Effective Equipment, LLC warrants to the original purchaser (Buyer) that equipment is free from defects in material and workmanship under normal use and service in accordance with Cee® instructions and specifications. Buyer shall promptly notify Cee® of any claim against this warranty, and any item to be returned to Cee® shall be sent with transportation charges prepaid by Buyer, clearly marked with a Return Authorization (RMA) number obtained from Cee® Customer Support. Cee's obligation under this warranty is limited to the repair or replacement, at Cee®'s option, of any equipment, component or part which is determined by Cee® to be defective in material or workmanship. This obligation shall expire one (1) year after the initial shipment of the equipment from Cee®. This warranty shall be void if:

- Any failure is due to the misuse, neglect, improper installation of, or accident to the equipment.
- Any major repairs or alterations are made to equipment by anyone other than a duly authorized representative of Cee®. Representatives of Buyer will be authorized to make repairs to the equipment without voiding warranty, on completion of the Cee® training program.
- Replacement parts are used other than those made or recommended by Cee®.

CEE® MAKES NO OTHER WARRANTIES, EXPRESSED OR IMPLIED, WITH RESPECT TO EQUIPMENT. NO WARRANTY IS MADE AS TO THE MERCHANTABILITY OF THE EQUIPMENT NOR ITS FITNESS FOR ANY PARTICULAR PURPOSE. In no event shall Cee® be liable for consequential loss or damages, however caused. No person or representative of Cee® is authorized to assume for Cee® any liability in connection with equipment nor to make any change to this warranty unless such change or modification is put in writing and approved by an authorized representative of Cee® in writing.

This warranty shall be governed by the laws of the state of Missouri, U.S.A.

1.3 Returned Materials

Any materials, parts, or equipment returned to Cost Effective Equipment, LLC must be clearly labeled with a Return Material Authorization (RMA) number.

To obtain an RMA number, contact:

Cee® Customer Support

1.4 Model and Revisions

The model and serial number information for the Cee® Apogee™ 300 Bake Plate are located on the rear panel. Software version information can be found on the *About* screen. Refer to the <u>DataStream™</u> <u>Manual</u> for screen shots and a detailed explanation of the system software.

1.5 Environmental Considerations



Cee® fosters sustainability through innovation in the durability and reliability of our precision tools and equipment. Individual component modules are engineered for serviceability ensuring long lasting performance. Processes are designed to minimize use & consumption of chemical compounds ensuring accurate, replicable, industry-leading results every time.



Cee® diligently screens suppliers to ensure conflict-free sourcing of minerals and product components are constructed of recycled materials wherever possible.



Cee® tools and equipment operate without the use of ozone depleting substances (ODSs) including chlorofluorocarbons (CFCs), methyl chloroform, hydrochlorofluorocarbons (HCFCs), carbon tetrachloride, perfluoro compounds (PFCs), or other volatile compounds/organic solvents.

1.6 General Safety Hazards / Precautions



Read this manual in its entirety before operating or servicing the machine.



The unit is very heaving and proper precautions should be taken when handling the machine to minimize risk of injury. Labels are placed on the machine to identify areas where caution is needed during operation.

1.7 Electrical



High Voltage is present in the machine. Disconnect power before servicing.



Stored electrical energy is present in the machine. Before servicing allow sufficient time for discharge.

1.8 Mechanical



This machine may contain compressed gases which can provide motive force for components and can expand violently upon decompression. Disconnect N_2 or CDA before removing any panels.



Ensure that all panels are on and in their correct locations before powering up or operating.



When opening lids be aware of the pinch point at the hinge cover. Open lids only by using the handles on the lids.

1.9 Thermal



Bake Plates can reach temperatures sufficient to cause severe burns and may remain hot for a long-time following operation. Do not service the machine until all surfaces have cooled to a safe thermal condition (e.g., room temperature).

1.10 Chemical



Ensure chemical compatibility of all chemicals and materials being used inside the machine. This includes all wetted parts of the storage, supply, dispense, and waste systems.



Flammable Chemicals. No open flames/sparks.



Relieve pressure and shut off chemical valves before servicing supply lines, dispense valves or other components.



Ensure proper ventilation/exhaust is always used.



Always wear appropriate Personal Protective Equipment. This includes safety glasses, gloves, and other equipment, as needed, to protect from mechanical and chemical hazards.

1.11 Lockout/Tagout Procedures and Information

Before servicing, turn off the machine and remove the power inlet cord by disconnecting the plug where it enters the machine.

<u>Note</u>: There are no LOTO (Lock Out/Tag Out) facilities supplied with the Cee® Apogee [™] 300 Bake Plate. It is the responsibility of the customer/installer/end-user to ensure that the suitable LOTO devices are provided on utilities being supplied to the Cee® Apogee [™] 300 Bake Plate in accordance with applicable laws, regulations, and/or company policies.

For more information, please contact **Cee® Customer Support**.

1.12 Intended Use of Machine

The Cee® Apogee™ 300 Bake Plate is intended for use as a semiconductor/optical application machine.

The Cee® Apogee™ 300 Bake Plate is not intended for use in food or medical applications or for use in hazardous locations.

The Cee® Apogee™ 300 Bake Plate is intended for use only by trained personnel wearing the proper personal protective equipment. Anyone not trained in the proper use of the Cee® Apogee™ 300 Bake Plate and having not fully read this manual, should not operate the equipment.

The Cee® Apogee™ 300 Bake Plate is intended for use in a cleanroom environment to provide the proper processing conditions for substrates. If it is used outside of a cleanroom environment, substrate cleanliness may be compromised.

The Cee® Apogee™ 300 Bake Plate is not intended for use in a hazardous or explosive environment.

2 **Equipment Description**

The Cee® Apogee™ 300 Bake Plate features a revolutionary intuitive interface, a space-saving design, and track-quality thermal accuracy and uniformity.

Fully programmable and user-friendly, the Cee® Apogee™ 300 Bake Plate features the accuracy and repeatability needed to eliminate processing variability from critical experiments. Recipes are easily entered, monitored, and stored with the convenient full-color touch screen interface and onboard DataStream™ Technology. Compact footprint, intuitive design, and unparalleled manufacturer experience add up to years of high-performance bake step processing, perfect for any low-volume or R&D laboratory processing environment.

2.1 User Controls

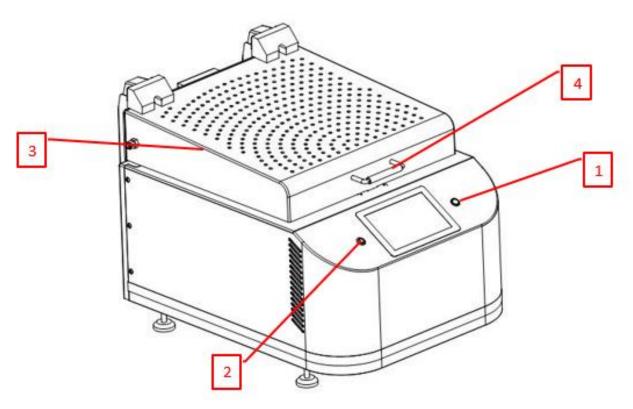


Figure 1: Cee® Apogee™ 300 Bake Plate User Controls

| 1. | power button | used to turn equipment off and on |
|----|-----------------------------------|---|
| 2. | user presence button ¹ | facilitates remote access |
| 3. | bake plate lid | cover for the bake plate working surface |
| 4. | lid handle | enables safe opening and closing of the lid |

2.2 Dimensions

- 18" (457.2mm) W x 18.75" (476.3mm) D x 26.25" (666.8mm) H
- machine weight......146lbs (29.5kg) excluding accessories

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¹ See <u>DataStream™ Manual</u> for more information

2.3 Features & Programmability

- compact design for minimized footprint
- 7" touch screen display with full-color alphanumeric-capable graphical user interface (GUI)
- durable wet bench design can be converted to a flange/deck mountable configuration
- supports unlimited bake process programs/program steps per recipe
- 0.1 second step time resolution (9,999.9 seconds maximum step time)
- three automated bake methods: contact, vacuum, proximity
- bake plate auto-sizing for 100mm, 125mm, 150mm, 200mm and 300mm substrates²
- up/download DataStream[™] process parameters via native USB and Ethernet ports
- program 10 specific proximity heights above surface in any sequence/combination
- height programmed in 0.1 increments with an overall range of 0-19mm
- exhausted hood for removal of process chemicals
- optional nitrogen purge for inert bake environment

2.4 Precision

• substrate sizes.....<10mm to 300mm round; 12" x 12" square

temperature resolution0.1°C

• temperature rangeambient to 300°C (400°C optional)

temperature uniformity± 0.3% across working surface

2.5 Reliability

industry-leading Cee® Apogee™ reliability and uptime

one-year full warranty on parts and labor

 complimentary remote technical support and application process assistance for the life of the product

2.6 Utilities

vacuumpump supplied

exhaust5-10cfm

• N₂......35psi

² Equipment may allow for custom sized substrates based on customer request.

3 Installation

3.1 Clearance Requirements

The Cee® Apogee™ 300 Bake Plate is a benchtop unit requiring a table or benchtop for location. In most cases the supporting structure will be larger than the unit itself.

Clearance Requirements



Figure 2: Apogee™ 300 Bake Plate Side Clearance Requirements

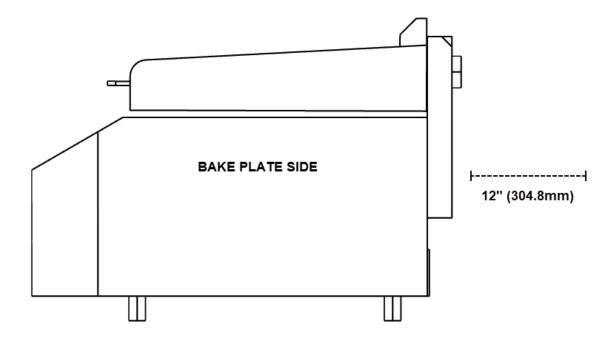


Figure 3: Apogee™ 300 Bake Plate Rear Clearance Requirements

3.2 Facilities Requirements

The Cee® Apogee™ 300 Bake Plate requires the following utilities for operation.

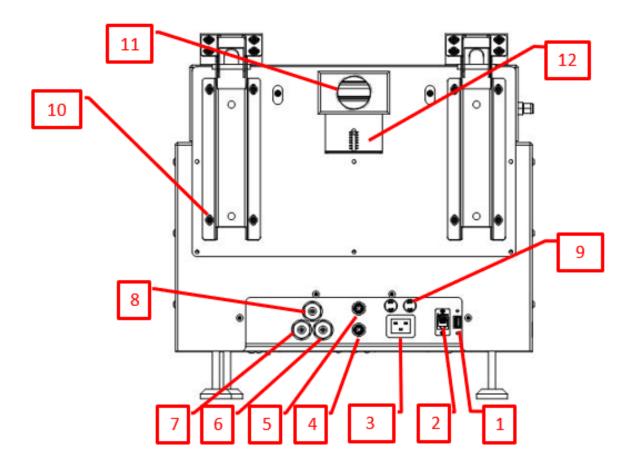


Figure 4: Apogee™ 300 Bake Plate Facilities Connections

| 1. | USB port | . facilitates software updates and log file downloads |
|-----|--------------------------|--|
| 2. | Ethernet | enables remote recipe writing remote device control |
| 3. | AC power in | . single phase AC power in |
| 4. | accessory port | enables communication with external I/O devices as needed |
| 5. | light tree | . port for optional light tree |
| 6. | vacuum accessory supply | connection for accessories items (e.g., vacuum wands) |
| 7. | system vacuum | . system vacuum for bake plate surface |
| 8. | system N ₂ | system nitrogen for proximity bake on the bake plate surface |
| 9. | fuses | . system surge protection fuses |
| 10 | . hood height adjustment | used to adjust the gap beneath the hood |
| 11. | . exhaust port | . exhaust port for bake plate vapors |
| 12. | . exhaust gate | used to adjust the flow rate of exhaust on the bake plate |

3.3 Environment

The Cee® Apogee™ 300 Bake Plate should be operated in a clean, low humidity environment.

3.4 Unpackaging & Inspection

- 1. Lifting from the bottom of the unit, carefully remove from packing crate. Do not lift by any of the top covers or protrusions. Do not roll or turn the unit on its sides.
- 2. Remove packing foam and plastic wrap.
- 3. Place the Cee® Apogee™ 300 Bake Plate on a table of proper height and strength so that the controls and bake surface are at an ergonomically appropriate height.
- 4. Thoroughly check the machine for shipping damage. If physical damage is apparent, **DO NOT APPLY POWER!** Contact **Cee® Customer Support** immediately.

The following items are included with shipment:

- Cee® Apogee™ Bake Plate
- (x2) stop pins
- temperature & humidity sensor
- power cord
- operations manual (USB thumb drive)
- quick reference card

Optionally Included Items:

- vacuum pump
- other equipment as specified by your sales order

3.5 System Installation & Setup

Please refer to the quick reference card supplied with the tool.

- 1. Using (x2) 9/16" wrenches, turn the adjustable feet until there is 1 ¼" − 1 ¾" between the tabletop and bottom of the equipment. Using the adjustable feet, first level the Cee® Apogee™ Bake Plate then adjust so that the bake surface tilts slightly back sufficiently that when using proximity mode the wafer floats against the stop pins and not off the front of the chuck.
- 2. Thoroughly clean the bake plate surface according to instructions outlined in the *Preventative Maintenance* section of this manual.
- 3. Connect utilities according to the Facilities Requirements diagram in section 3.2.
- 4. Connect the temperature & humidity sensor to the CAN terminal.
- 5. Connect the vacuum supply to the vacuum fitting.
- 6. Connect the nitrogen supply to the nitrogen fitting.
- 7. Connect exhaust lines to the exhaust port.
- 8. Plug in the machine and note that only the cooling fan should be powered, not the display.

3.6 Start Up

Once the preliminary setup steps outlined in section 3 have been completed, press the lighted *Power* switch to turn the tool on. The display will cycle through a series of boot screens before arriving at the main login screen.

Enter default administrative login credentials:

| Username: | admin |
|-----------|------------|
| Password: | admin2 |

3.7 System Checks

On the **Process** screen, navigate to **Tools>Manual Control** and perform the following system checks for initial validation of the Cee® Apogee™ 300 Bake Plate.

Set Lift Pins

Select a **Control** of **Lift Pins** and an **Action** of **Set**. Enter a value into the **Height** field and tap **Apply**. Verify **Lift Pin Height** readings respond to changes on the **System Values** list.

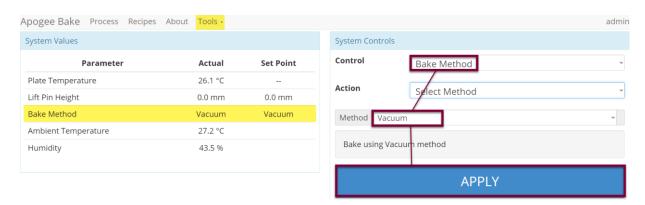


Inset supplied stop pins into the desired holes on the bake plate surface. These stop pins keep the substrate centered on the bake plate surface. Holes closest to center are for 100mm substrates. From center, stop pin locations are for 100mm, 125mm, 150mm, 200mm, 300mm substrates respectively.

Bake Methods

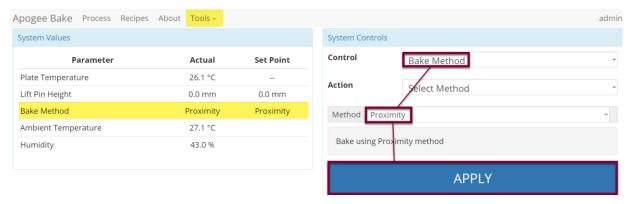
Vacuum

Set **Bake Method** to **Vacuum**. Place a substrate on the center of the bake plate and check that the vacuum holds the substrate.



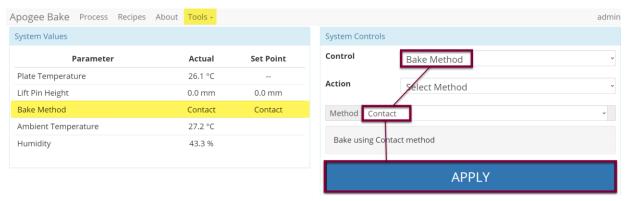
Proximity

Set **Bake Method** to *Proximity*. This will turn off the vacuum and purge N_2 to float the substrate above the bake plate surface.



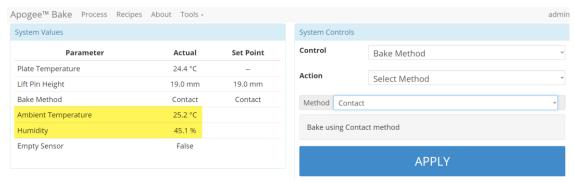
Contact

Set the **Bake Method** to **Contact**. This will turn off vacuum and N₂. Remove the substrate.



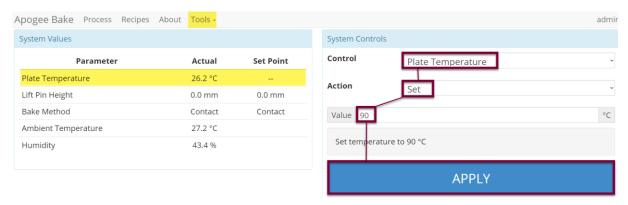
Temperature & Humidity Sensor

Ensure the temperature & humidity sensor is functioning by verifying that *Ambient Temperature* and *Humidity* readings are present on the *System Values* List.

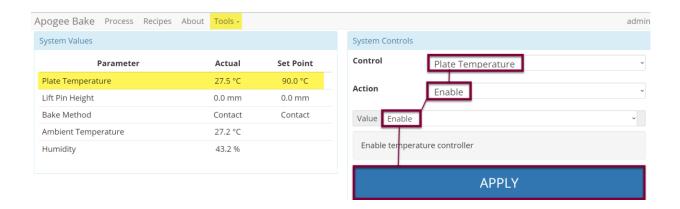


Enable & Test Plate Temperature

Use the **Control** drop-down to select **Plate Temperature** then select an **Action** of **Set**, enter the desired plate temperature for your application, and tap **Apply**. *Note that the **System Values** list displays a Set Point of null (--).



Change the **Control** selection to **Plate Temperature** then select **Enable** from the **Action** and **Value** dropdowns and tap **Apply.** Note that the temperature entered in the previous step is now displayed as the **Set Point** in the **System Values** list. The **Actual** temperature in the **System Values** list will increase/decrease as the bake surface heats/cools.



Once these operations have been validated, the Cee® Apogee™ 300 Bake Plate is ready for use. Begin by creating a recipe. Refer to the <u>DataStream™ Manual</u> for more information and refer to section 4 of this manual for Bake Plate specific DataStream™ features.

4 DataStream™ Technology

This section covers information specific to the Apogee[™] 300 Bake Plate and is intended as a companion to the DataStream[™] Technology Software Manual. *Please review the DataStream*[™] *Operations Manual* for detailed guidance on software usage.

4.1 System Parameters

| Pa | rameter | | Actual | Set Point | Status |
|--------------------------------|-------------|-------------|---------------|------------------------|------------------------|
| Plate T | emperature | | 59.4 °C | 60.0 °C | In Range |
| Lift I | Pin Height | | 19.0 mm | 19.0 mm | In Range |
| Bak | e Method | | Contact | Contact | In Range |
| Ambient | Temperature | | 26.5 °C | | In Range |
| Н | umidity | | 44.8 % | | In Range |
| Plate Temperature ³ | | the current | temperature o | f the hot chuck displa | ayed against the targe |

Plate Temperature³ the current temperature of the hot chuck displayed against the target set

point in degrees Celsius

Lift Pin Height the height of exposed lift pins in relation to the chuck in millimeters;

precision control settings range from 0.0-19.0

Bake Method dictates the manner in which the substrate is heated; vacuum, contact,

proximity, lift pins.

Ambient Temperature the air temperature of the environment where the equipment is housed

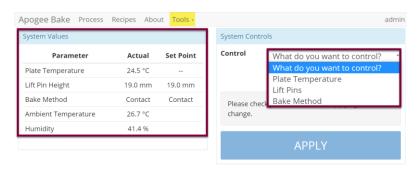
Humidity⁴ the ambient relative humidity in the environment where the equipment is

housed

4.2 Manual Controls - Apogee™ 300 Bake Plate

The **Manual Control** activity is an advanced feature that allows users to run most operating processes outside of a recipe. This mode is useful for tasks such as prototyping processes, verifying equipment operation, and recovering from aborted processes. To access the activity, navigate to **Tools > Manual Control**. Actual and set point parameter values are displayed on the left. Available controls will be selected from the dropdown menu on the right.

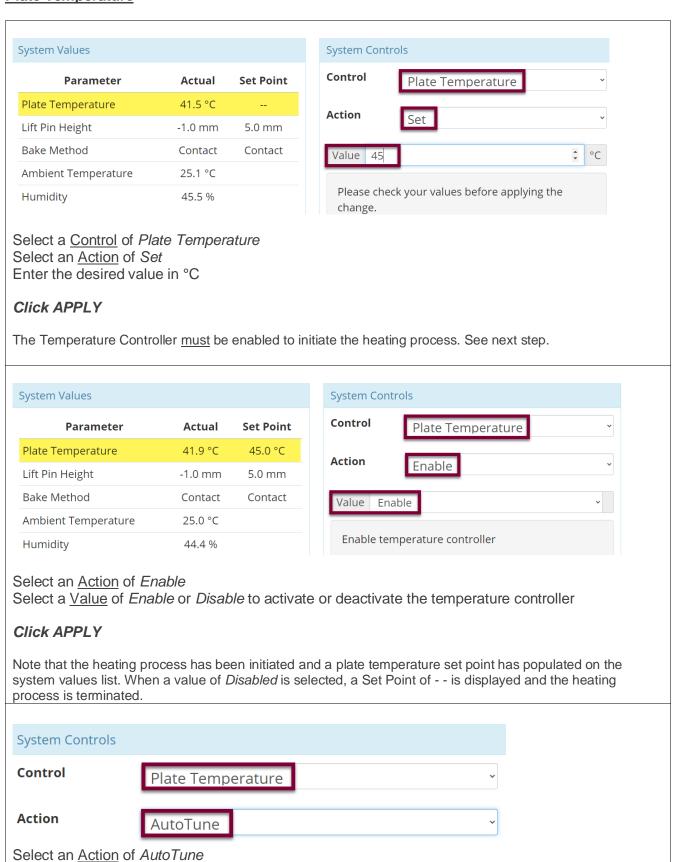
If using remote feature, the user must confirm local presence to execute manual commands. Refer to the DataStream ™ Manual for guidance on the Local Presence feature.



³ A process will not wait to achieve desired temperatures before moving onto the next step. Utilize preconditions or manual controls to ensure platen temperatures are in range before a process is initiated.

⁴ Both Ambient Temperature and Humidity are measured via a custom sensor board mounted next to a ventilation inlet inside the tool. If sensor is disconnected, default of -1.1 is displayed.

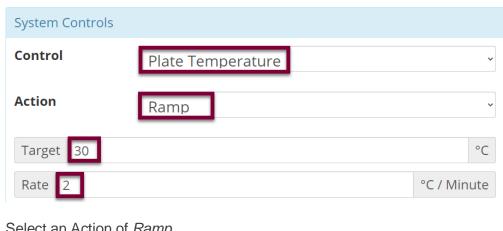
Plate Temperature



Click APPLY

User must first define the set point and enable temperature controller.

Useful for refining the temperature control for a given setting – note that this may take a significant amount of time.

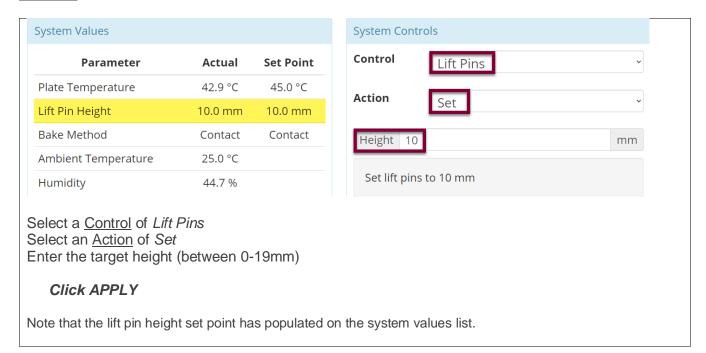


Select an <u>Action</u> of *Ramp*Enter the <u>Target</u> temperature

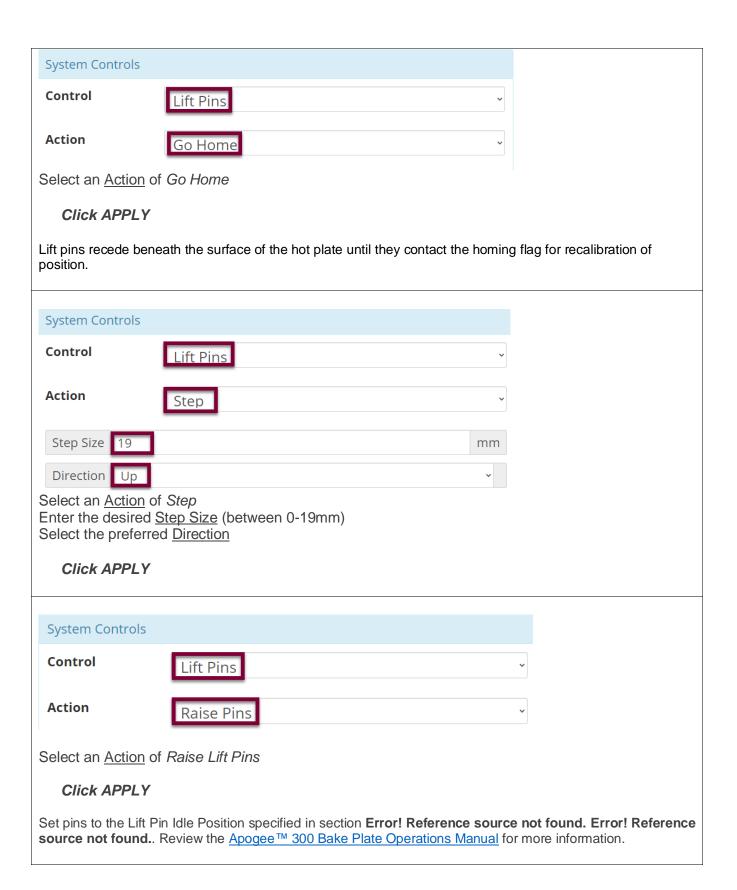
Enter the desired ramp Rate⁵ (between 1-6°C per minute)

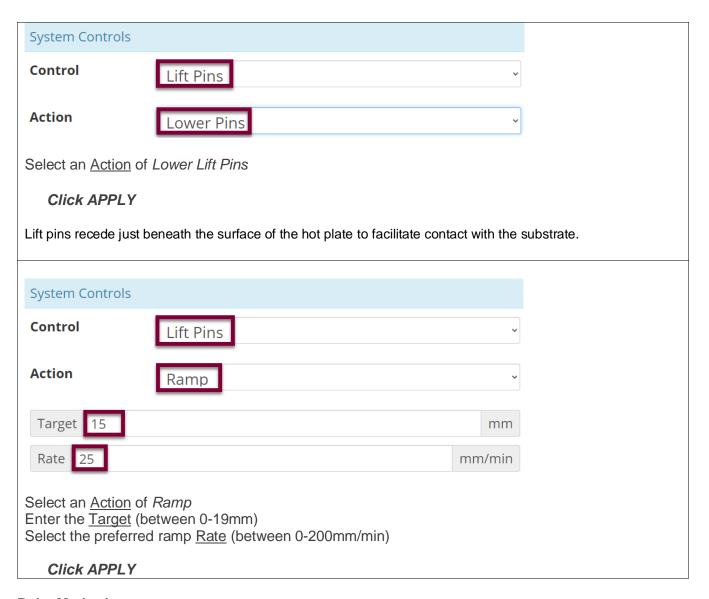
Click APPLY

Lift Pins

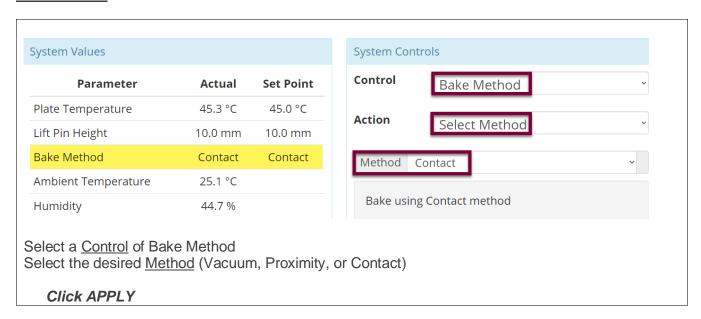


⁵ Cee® does not offer active cooling on bake plates however, the ramp feature can be used to reduce the rate of cooling beyond what ambient conditions allow.





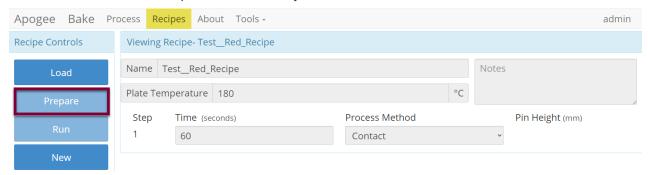
Bake Method



Review the Apogee™ 300 Bake Plate Operations Manual for more information on Bake Methods.

4.3 Preparation

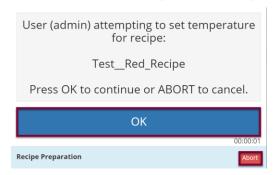
Users with sufficient privileges can *Prepare* equipment to run a recipe. This feature is useful for preconditions and parameters that take a significant amount of time such as hot chuck and platen temperatures. To initiate this feature, navigate to the *Recipes* tab, click *Load* to access the recipes list and select the desired recipe, then click *Prepare*.



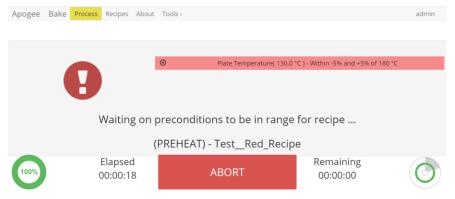
*Preparation processes cannot be initiated when the equipment is already in use.

<u>Local Display</u> – When a *Prepare* command is entered, the user or device with active control of the machine receives an alert. This prompt includes the user and recipe to be prepared. The user with control of the machine can refuse the request by selecting *Abort* or accept the request by tapping *OK*.

In the absence of a response, the request is auto accepted after two minutes.



<u>Preparation In Process</u> – progress toward the specified precondition(s) is displayed to the user with verified local presence.



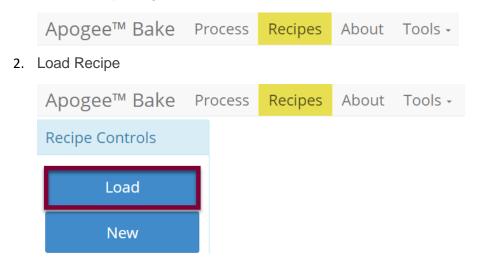
<u>Preparation Complete</u> – indicates that the equipment has reached all specified preconditions and the recipe can be initiated. Upon clicking **OK** the user is directed to the *Process* screen to begin the recipe.



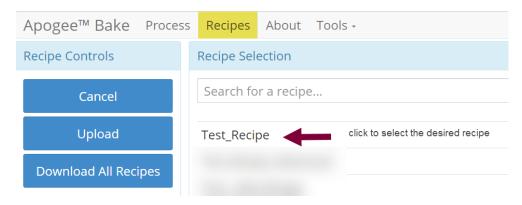
*During recipe preparation the Prepare and Run commands are disabled to ensure no interruption to precondition processes.

4.4 Running Recipes

Select Recipe Page



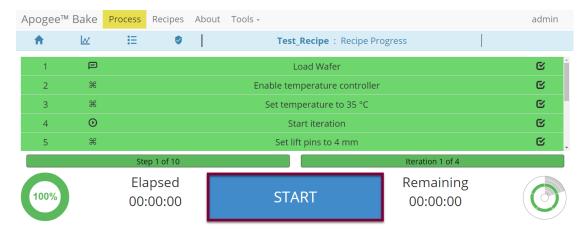
3. Search For, Identify, & Select Recipe



4. Run Recipe



5. Start Recipe

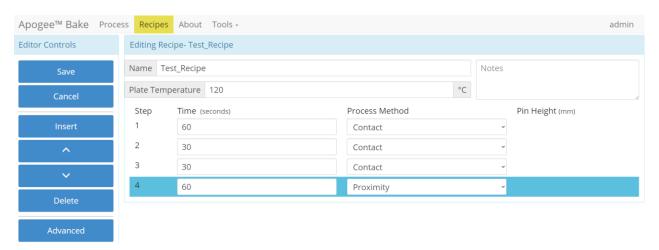


6. Recipe Progression



^{*}Users may be required to follow prompts on the screen during recipe execution.

4.5 Editing Recipes



4.6 Tool Specific Settings - Apogee™ 300 Bake Plate

Temperature Offset Calibration (°C)

Offset used by the temperature controller to calibrate the reported chuck temperature

User defined height of lift pins upon machine start-up and after recipe completion *default value 19mm

Lift Pin Offset (mm)⁶

Offset can be supplied for calibration of lift pin positioning

Page **22** of **30** Doc Rev 2.20221109

⁶ Offset impacts all lift pins.

5 Bake Plate Theory

Hotplate bake processing has increased in popularity since the early 1980s. Previously the most common technique for film drying and curing was the convection oven. Bake plates, also known as hotplates, offer several advantages in the form of increased throughput, increased uniformity and reproducibility, and decreased particle contamination. In a typical bake process, the substrate quickly rises to temperature. Drying and curing steps generally take about one minute. This contrasts with traditional oven processes which generally take thirty minutes or more.

5.1 Bake Plates vs Conventional Ovens

Bake plates have several advantages over conventional ovens.

- decreased bake time
- increased reproducibility
- better film quality

This section will describe these differences and set a few guidelines for using bake plates.

Stratification, the formation of different temperature zones, is a problem associated with convection ovens and can severely affect film quality and reproducibility.

The heating rate of a substrate in an oven depends not only on the heated air flow past a substrate but also on its proximity to other cold substrates. Thus, the heating rate for each substrate in a cassette of substrates that are being baked will be less than if each substrate is baked alone.

In addition, substrates near the ends of a cassette heat faster than the substrates in the middle, producing a non-uniform heating.

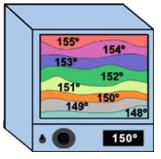
Particle generation also occurs within a standard oven. In a forced-air convection oven, substrates are commonly exposed to a flow of particle laden air for at least thirty minutes.

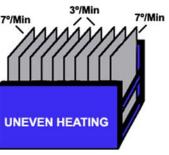
During resin film cures, the substrates will be exposed to considerable particulate contamination. The substrates are vulnerable since the film may still contain solvents and during this *soft* state the film is very susceptible to having particle adhere to it.

5.2 The Skin Effect

Another disadvantage of normal oven baking results from baking substrates from the *outside in*. Since heat is applied to the outer surface of the film first, a skin forms on the surface of the film, trapping solvents. Upon vaporizing, these solvents form blisters or bubbles which results in adhesion loss or even bulk film failure. This problem prevails in processes involving thick film resins, e.g., polyimides.

No skin effect occurs on a hotplate since hotplate baking heats the substrate from the bottom up. This *inside out* approach offers advantages for thick films since solvents in the film nearest the substrate are baked off before the film surface seals over.







5.3 Hotplate Bake Variables and Methods

A typical bake process consists of preheating the surface to a known temperature, loading the substrate onto the surface for a specific length of time and removing it promptly at the end of the cycle. The selection of the temperature and time values used as well as the bake method employed all affect the overall performance of the process.

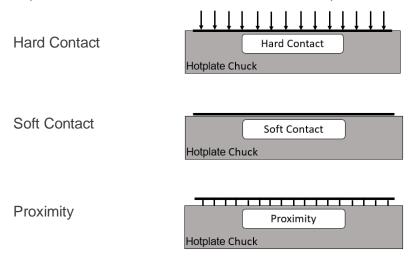
5.4 Bake Temperature

The bake temperature used is dependent on several factors. The material and substrate being baked as well as the results desired are key factors to be considered in developing a bake process

In general, hotplate baking will be performed at temperatures slightly higher than those used in oven bake processes. The film being baked will reach a temperature somewhere between the temperature of the hotplate and the ambient air above the film. As an example, with a hotplate surface temperature of 115°C, a layer of photoresist on a silicon wafer will reach a final temperature of about 105°C after a few seconds. Thicker substrates and/or substrates with lower coefficients of thermal conductivity will require even higher temperatures to compensate for this phenomenon.

5.5 Bake Methods

Another important factor is the method of bake. Cee® hotplates allow for three distinct bake methods:



In a hard contact bake, the substrate is held onto the hotplate surface by the application of vacuum to the underside of the substrate. Small holes are machined into the hotplate surface in a pattern which optimizes vacuum distribution without the formation of cold spots or warping of the substrate. This method is usually preferred for silicon and other flat substrates where back side contact is not a problem.

Soft contact baking uses gravity alone to hold the substate to the hotplate. This method generally offers less uniformity since the substrate-hotplate thermal interface is not as efficient.

Proximity baking is accomplished by forcing nitrogen through ports in the hotplate surface. This forces the substrate to float at a distance of one to four millimeters (25-100µm) above the hotplate surface. Proximity baking allows for a slower warm-up than contact bake methods and can be advantageous when baking thick films where blistering would otherwise be a problem.

Another advantage of proximity baking is that often, cambered, or warped substrates can be baked with a high degree of uniformity. This is usually not possible with the contact methods since it is not possible to achieve a vacuum under a substrate that is not flat to start with. Processing cambered substrates

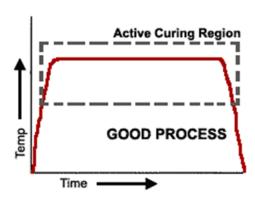
with the soft contact method creates hot spots where the substrate touches the hotplate and cold spots where it does not. It should be noted as well that this type of proximity process is *self-leveling* in that substrate will tend form a uniform gap to the hotplate surface.

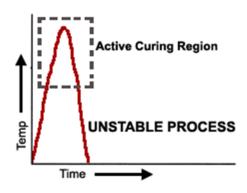
Proximity baking also offers the unique advantage of allowing hotplate processing without touching the bottom side of the substrate. An example of this application is photomask processing. In processing these relatively thick glass plates it is important that the backside of the glass not directly touch the hotplate since rapid heating will cause micro-fractures in the glass. By performing the entire bake process in proximity mode, the integrity of the substrate is not endangered, and the uniformity is excellent.

5.6 Bake Time

The selection of the bake time parameter plays an important role in the reproducibility of the bake process. Substrate thermal properties and the choice of bake method greatly affect the amount of time necessary for the substrate, and therefore film temperature, to stabilize during the bake. Thicker substrates and the use of proximity bake methods will increase the time necessary for the film to reach its final temperature. It is important that most of the baking action in the film take place after this temperature is reached. A silicon wafer will reach a stable temperature within a few seconds and so it is traditional to adjust photoresist bake processes to be completed in 60-90 seconds with an appropriate bake temperature.

For thicker substrates such as photomask and ceramic modules, the increased time necessary to heat the larger mass of the substrate results in bake times approaching five minutes. It should be noted that these substrates can be processed with higher temperature and shorter bake times, but reproducibility may suffer. If the bake time is too short, a significant amount of the actual bake process will take place during the loading and unloading steps as well as while the substrate is cooling after removal from the bake plate. This is an unstable condition since it is very difficult to exactly reproduce conditions during these steps.

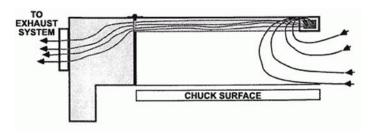




In general, the temperature-time relationship in a bake process can be taken as a dose of the (temperature) x (time) product. Increasing the bake temperature results in a need for decreasing bake time. The limits for both parameters can be reached when the process is no longer reproducible or when the physical temperature limitations of the resin or substrate have been reached.

5.7 Exhaust Cover

The design of the Cee® exhaust cover promotes dissipation of vapors removed from a substrate placed on the chuck, without drawing air across the chuck surface.



5.8 Oven vs Bake Plate Examples

The chart below presents process examples for commonly used resins. These figures should <u>not</u> be used as a rigid guideline since the best method with a particular baking application can only be achieved through experimentation.

Application

Positive Photo Resist

Oven Bake

90°C, 30 minutes, Polyimide beta (partial imidization)

135°C, 30 minutes, Polyimide alpha (solvent removal)

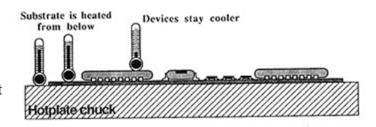
Hotplate Bake

115°C, 30 seconds, hard contact bake, Polyimide beta (partial imidization)

150°C, 15 seconds, proximity bake, 150°C-90 seconds, hard contact bake, Polyimide alpha (solvent removal)

5.9 Reflow Soldering

Bake plate processing heats the substrate and the solder without applying heat directly to the devices on the board. Using a combination of proximity and hard-contact bakes, the bake profile can be adjusted to suit any process.



5.10 Bake Plate Process Troubleshooting

As with spin coating process, there are no absolute rules for bake plate processing, only general guidelines. The following is a list of issues to consider for specific bake plate process problems.

Film overbaked

| bake temperature too high | reduce temperature |
|---------------------------|--------------------|
| bake time too long | decrease bake time |

Film underbaked

| bake temperature too low | increase temperature |
|--------------------------|----------------------|
| bake time too short | increase bake time |

Film blistering or cracking

| unstable balance in temp/time parameters | decrease temp/increase time |
|--|---|
| warm-up time too fast | use proximity bake to preheat substrate |

Non-uniform bake

| unstable balance in temp/time parameters | .decrease temp/increase time |
|--|-------------------------------------|
| operating with exhaust lid raised | .lower the exhaust lid |
| unstable ambient conditions | .protect against major fluctuations |
| bake time too short | .increase bake time |
| bake plate surface contaminated | .clean surface of bake plate |

6 Preventative Maintenance

This section provides personnel with procedures and guidelines for maintaining a Cee® Apogee ™ Bake Plate.

6.1 Safety Checks

Inspect bake plate lid for the following defects:

- loose assemblies
- improper closure
- improper exhaust connection

6.2 Mechanical/Utilities Checklist

| <u>Evaluate</u> | Frequency | <u>Detail</u> |
|-------------------------|-------------|---|
| Utility Gasses & Vacuum | Daily | Check all gas pressures and vacuum for ranges specified in tool manual. |
| Exhaust | Daily | Verify that the exhaust is functional with adequate flow. |
| Bake Plate Surface | Weekly | Buildup of material on the bake plate can cause vacuum errors. For minor build-up wipe the bake surface clean with isopropyl alcohol or acetone. For major build-up of material, utilize a glass slide held at a 45° angle to <i>gently</i> scrape the material away then wipe clean with isopropyl alcohol or acetone. |
| Lift Pin Height | Quarterly | If the three lift pins are not lifting the wafer programmed amount of distance from the bake plate surface, they may require calibration. See section Error! Reference source not found. for details. |
| Power | Bi-Annually | Verify that AC power is connected and of the proper voltage. |

6.3 Cleaning

The Apogee™ 300 Bake Plate should be cleaned following daily use and only after the equipment has cooled to a safe thermal condition. The cabinet should be cleaned with isopropyl alcohol. When cleaning the hot plate surface, it is good practice to use the mildest solvent possible such as acetone or isopropyl alcohol. **Do not use caustic acids or bases.** For major build-up of material, utilize a glass slide held at a 45° angle to gently scrape the material away then wipe clean with isopropyl alcohol or acetone. Please visit the Cee® YouTube Channel for a demonstration. If these methods are unsuccessful contact Cee® Customer Support for additional guidance.

Use only water-based cleaner on the labels on the rear of the machine. Use only isopropyl or water-based cleaner on the Power, Cee® logo, Caution ... Eye Protection, and the Cee® model/serial number labels. The display may be cleaned with glass cleaner, water, or isopropyl alcohol.

7 Table of Revisions

| Doc Rev # | Author | Description of Change(s) | Reviewed/Approved By | Date |
|--------------|----------|--|--------------------------------|------------|
| 2.0 | J. Adams | update format add section 3.1, Clearance Requirements add section 4, DataStream™ Technology add section 7, Table of Revisions | B. Waterworth J. Strothmann | 11/09/2022 |